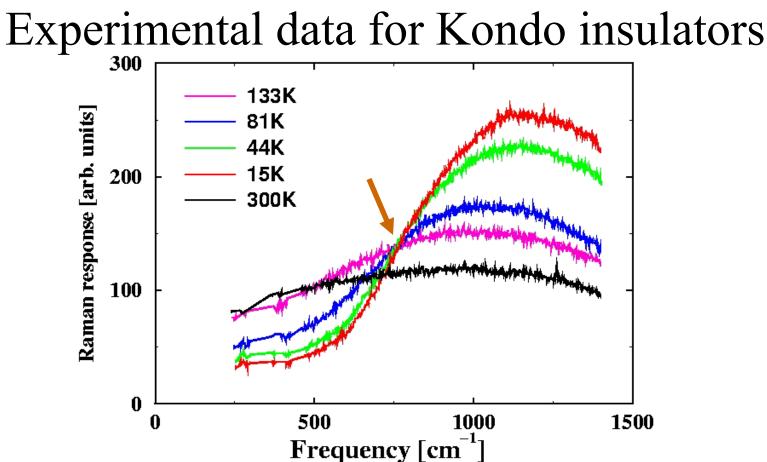
Inelastic Light scattering and the correlated metal-insulator transition

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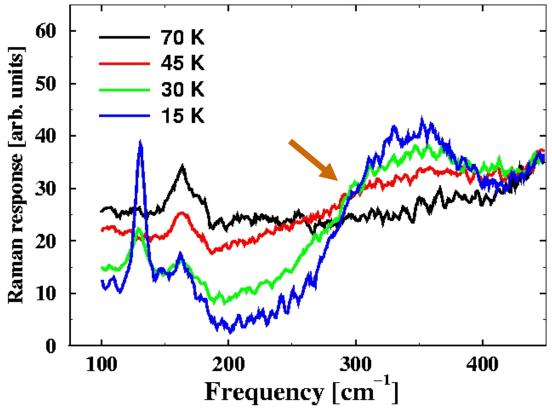
Raman scattering probes electronic excitations

- **Inelastic scattering of light** with electron-hole excitations of the correlated many-body system.
- Use of polarizers for the incident and reflected light allows one to **select different symmetries** of the electron-hole excitations.
- Signal depends on the Raman scattering amplitude γ(k).
 We consider three different symmetries here:
- A_{1g} : $\gamma(k) \sim \cos(k_x a) + \cos(k_y a)$
- B_{1g} : $\gamma(k) \sim \cos(k_x a) \cos(k_y a)$
- B_{2g} : $\gamma(k) \sim \sin(k_x a) \sin(k_y a)$



- *Nyhus et al, PRB 95* Raman scattering on **FeSi**. Note the appearance of the **isosbestic point** below about 150K.
- The low frequency spectral weight is **reduced** and the higher frequency weight is **enhanced** as the temperature is lowered.

Experimental data for intermediate-valence materials



- Nyhus et al, 1995 and 1997 Raman scattering on SmB₆.
 Note the appearance of the isosbestic point near 300 cm⁻¹.
- Below 30K, there is an **increase** in low frequency spectral weight in a narrow peak at about 130 cm⁻¹.

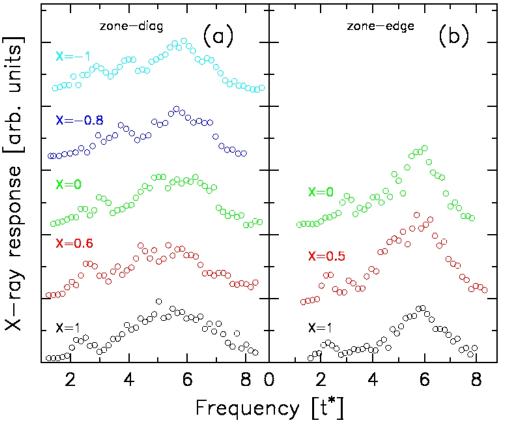
Summary of Experimental Data (Raman)

- Three characteristic behaviors are seen: (i) as T is lowered, there is a **redistribution of spectral weight** from lowfrequency to high frequency; (ii) these regions are separated by an isosbestic point, where **the Raman response is independent** of T; (iii) the ratio of the twice spectral range where spectral weight is depleted to the onset temperature, where it first is reduced, is **much larger than 3.5** (typically 10-30).
- For correlated insulators this behavior is "**universal**" in the sense that it **does not depend** on the microscopic properties of the insulating phase, be it a Kondo insulator or an intermediate-valence material.

Resonant Inelastic X-ray Scattering probes momentum and energy dependent charge excitations

- By **tuning** the photon energy to the K or L₃ edge of a core state, one finds large enhancements to the inelastic scattering.
- Advanced light sources have linearly polarized light, but experiments to date have not used polarizers on the detectors. Hence **different symmetry channels are mixed together** in the experimental results.
- The scattered signal depends on the **Raman scattering amplitude** $\gamma(\mathbf{k}+\mathbf{q}/2)$ for transferred momentum \mathbf{q} .
- The energy resolution in current experiments is poor (about 0.1ev) but is expected to improve dramatically with second-generation experiments (less than 20 meV).

RIXS on CaCu₂O₂Cl₂



RIXS data from Shen's group, Hasan et al., *Science* 2000. Experimental data on a Mott insulator shows a **broad chargetransfer peak** and a **dispersive low-energy peak**.

We label the transferred momentum by the parameter $X(\mathbf{q})=[\cos q_x + \cos q_y]/2$. When plotted in this fashion, the dispersion along the zone diagonal and zone center is **similar**.

The difference for X=1 along the different zone axes occurs due to the relation between the polarization vector and **q**, which **differs** for the different directions.

Summary of Experimental Data (RIXS)

- RIXS experiments on correlated insulators typically show two features---(i) a large-weight charge-transfer peak and (ii) a lower-energy peak. The charge transfer peak shows little dispersion through the Brillouin zone, while the lower-energy peak does disperse. The dispersion from the zone center to zone corner is usually about twice the dispersion from the zone center to the zone edge boundary.
- Experimental results project onto different weights of the different symmetry channels due to a locking of the photon momentum direction to the polarization of the electric field.
- Systematic changes in temperature **have not** been carried out yet.

Spinless Falicov-Kimball Model

$$H = -\frac{t}{2\sqrt{d}} \sum_{\langle i,j \rangle} c^{\dagger}_{i} c_{j} + E \sum_{i} w_{i} + U \sum_{i} c^{\dagger}_{i} c_{i} w_{i}$$

$$\downarrow \qquad \downarrow \qquad <- \text{ static spin } w_{i}$$

mobile spin ->
$$\downarrow \qquad \downarrow \qquad \downarrow \qquad U$$

•exactly solvable model on a hypercubic lattice in infinite dimensions using dynamical mean field theory.

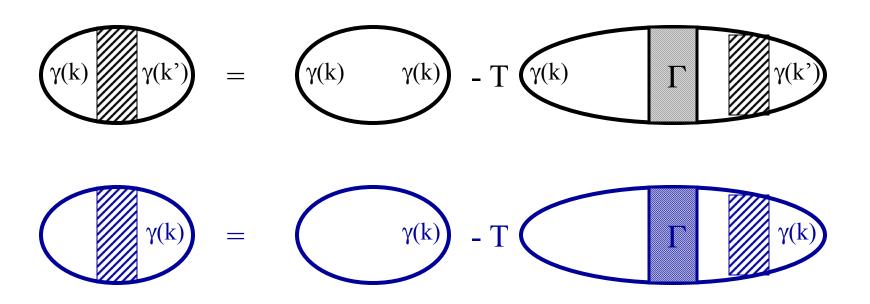
•possesses homogeneous, commensurate/incommensurate CDW phases, phase segregation, and **metal-insulator transitions**.

•Raman response can be constructed formally exactly.

Formal Solution for the Raman Scattering Response A_{1g} channel

- This channel has the **full symmetry** of the lattice
- The Raman response contains **resonant**, **mixed** and **nonresonant** terms. (We consider only the **nonresonant** terms here).
- The irreducible charge vertex for the Falicov-Kimball model is a simple function of the electronic self energy and Green's function (Shvaika, Physica C, 2000; Freericks and Miller, PRB, 2000). *This is not true for the Hubbard model*.
- The **nonresonant** Raman response can be determined **exactly** by properly solving the relevant Dyson equations.
- We illustrate how to solve this problem using **Feynman diagrams**.

Diagrams for the A_{1g} Raman response



 $\gamma(k) = -\epsilon(k)$, Γ is **local** and has no k-dependence

Solving these coupled equations allows for the full nonresonant Raman response to be determined.

Formal Solution for the Raman Scattering Response B_{1g} channel

- This channel is **orthogonal** to the lattice.
- There are **no vertex corrections** (Khurana, PRL, 1990), so the Raman response is represented by the **bare bubble**.
- This response is **identical** to that of the optical conductivity multiplied by one factor of frequency (Shastry and Shraiman, PRL, 1990).
- **Resonant** Raman scattering is possible in this channel, but won't be analyzed here.

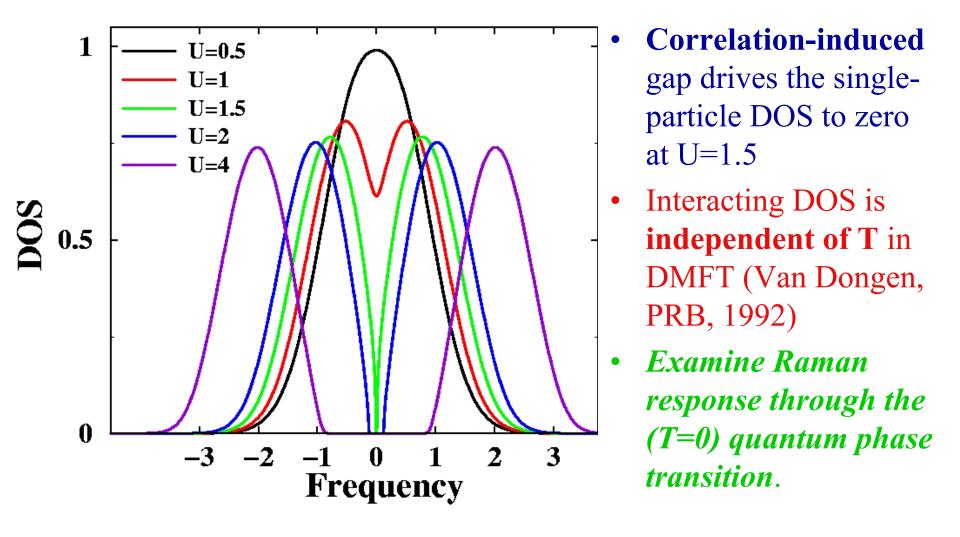
The nonresonant B_{1g} Raman response is closely related to the optical conductivity.

Formal Solution for Raman the Scattering Response B_{2g} channel

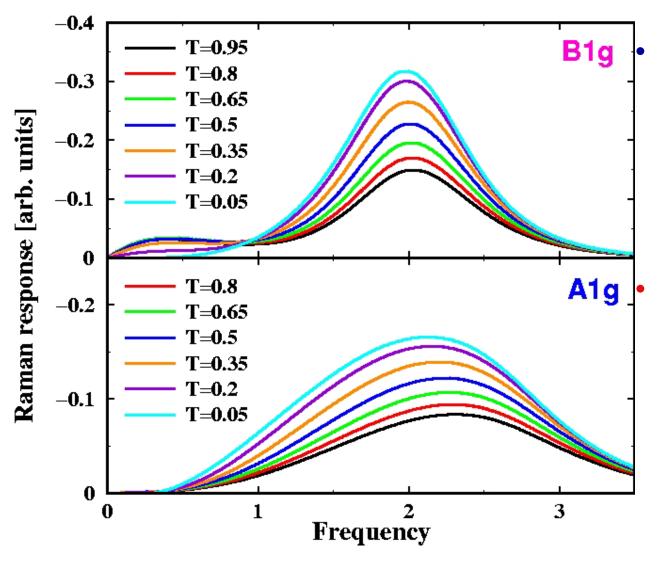
- The Raman scattering amplitude vanishes for nearest neighbor hopping on a hypercubic lattice, so there are **no nonresonant or mixed responses**.
- The square of the current operator does contain B_{2g} symmetry, so **pure resonant processes are possible**.
- Vertex corrections are needed, but are relatively simple to handle.
- We don't discuss this channel further here.

B_{2g} Raman scattering is purely resonant.

Metal-Insulator transition

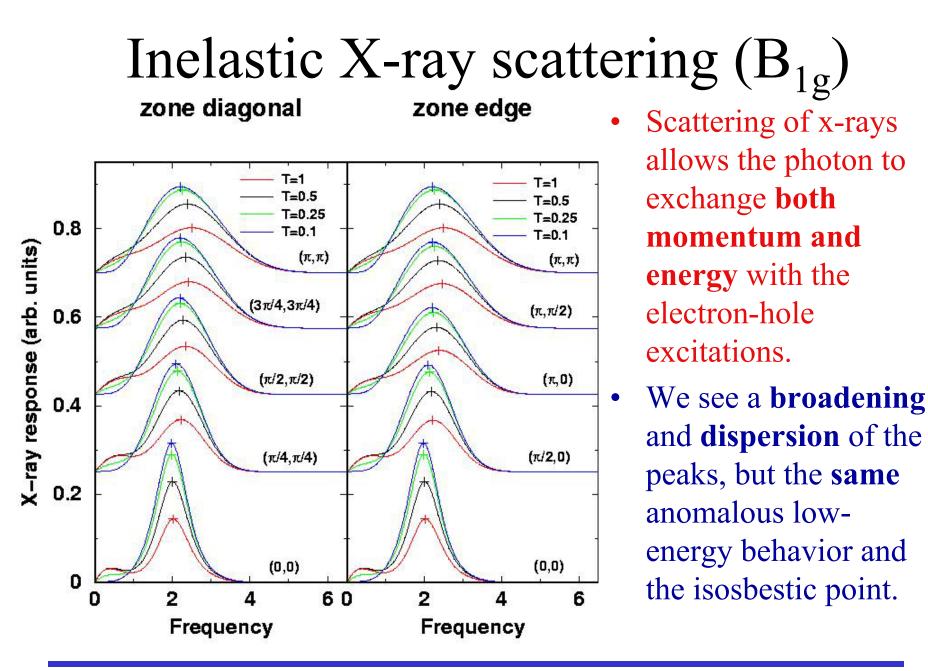


Nonresonant Raman Response (U=2)

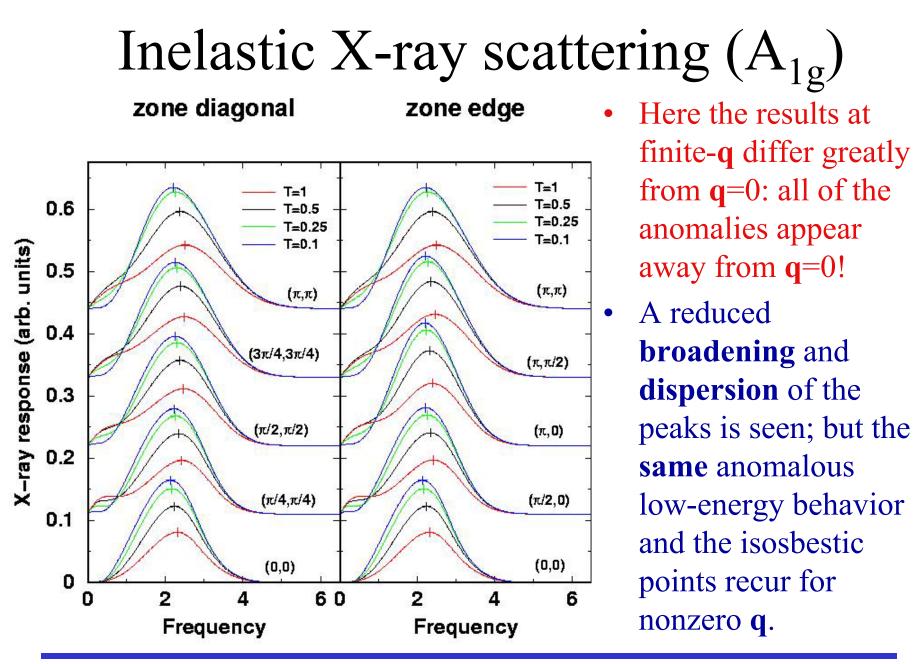


The low-frequency B_{1g} response develops at a low temperature over a wide frequency range of O(1). An isosbestic **point** divides where spectral weight increases or decreases as T is lowered (B_{1g}) .

J. K. Freericks, Georgetown University, Raman scattering talk, 2002



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Summary (Falicov-Kimball model)

- The theoretical results are **qualitatively similar** to experimental results measured in correlated systems.
- The nonresonant B_{1g} channel displays (i) an isosbestic point that divides the regions where the Raman response increase or decrease as T is lowered; (ii) a sharp depletion of spectral weight in the low-frequency region as T is reduced; and (iii) the temperature where low-frequency spectral features appear is much lower than the range in frequency over which those features appear.
- Results for the Raman scattering are **model independent** on the insulating side of the MIT.
- Vertex corrections suppress all nontrivial behavior for the A_{1g} channel at q=0 only.

Hubbard Model

$$H = -\frac{t}{2\sqrt{d}} \sum c_{i\sigma}^{*} c_{j\sigma} + U \sum n_{i\uparrow} n_{i\downarrow}$$

$$\uparrow \downarrow \uparrow \uparrow \downarrow \uparrow \downarrow$$

$$\downarrow \uparrow \uparrow \downarrow \downarrow \downarrow$$
Both electrons are no

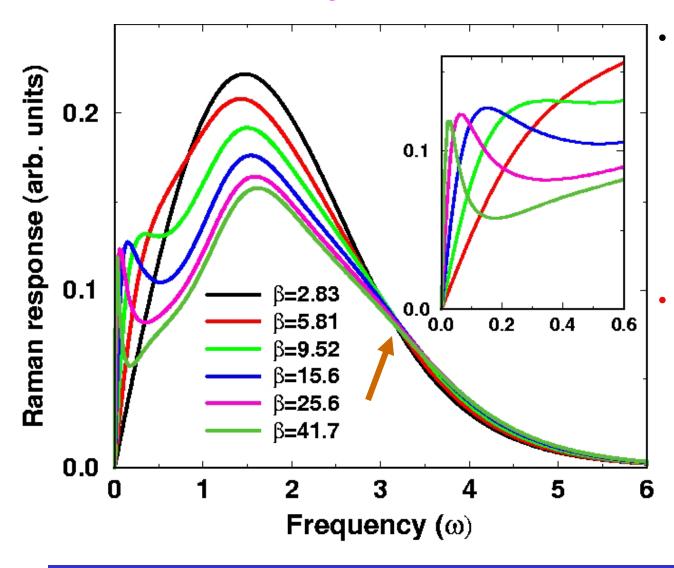
•Exactly solvable model on a hypercubic lattice in infinite dimensions using dynamical mean field theory (but requires NRG) calculations to extract real frequency information).

Both electrons are now **mobile**

•The irreducible charge vertex is **problematic to calculate** because it possesses too large a dynamic range for the max-ent techniques.

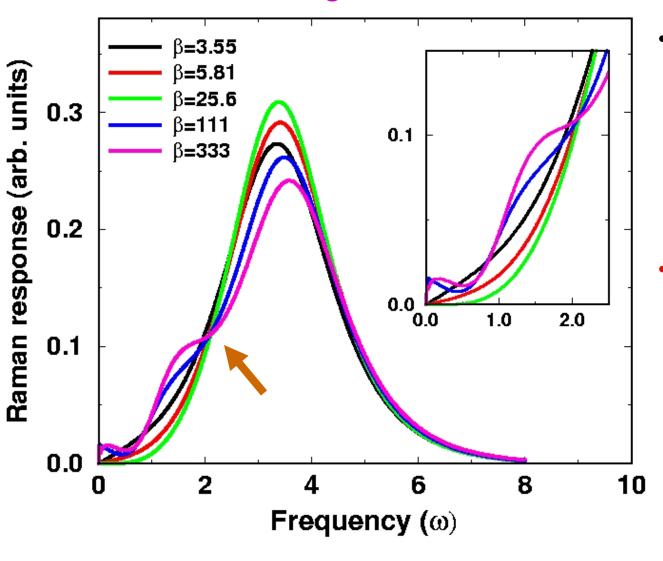
•Hence, the Raman response can be constructed formally exactly for the nonresonant B_{1g} channel only.

Nonresonant B_{1g} Raman scattering (n=1,U=2.1)



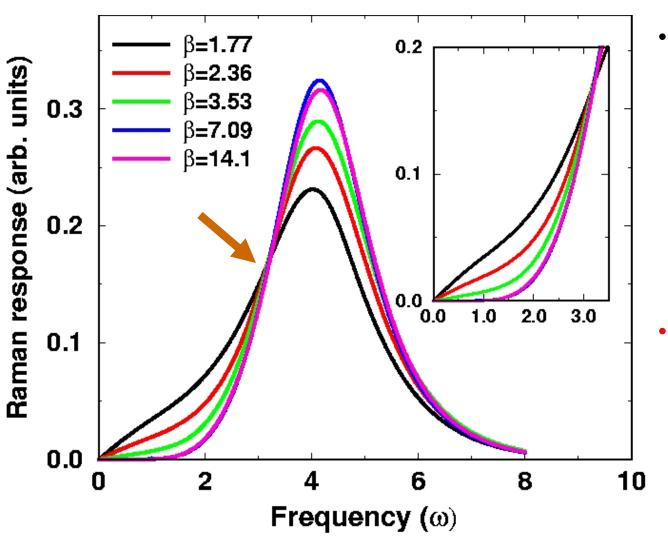
- Note the charge transfer peak as well as the Fermi liquid peak at low energy. As T goes to zero, the Fermi peak sharpens and moves to lower energy, as expected.
- There is **no low energy and low-T isosbestic point**, rather a high frequency isosbestic point seems to develop.

Nonresonant B_{1g} Raman scattering (n=1,U=3.5)



- This is **quite anomalous**! A MIT occurs as a function of T. Note the appearance of the low-T isosbestic point.
- The low energy
 Raman response has
 rich behavior, with a
 number of low energy
 peaks developing at
 low-T, but the low
 energy weight
 increases as T
 decreases here.

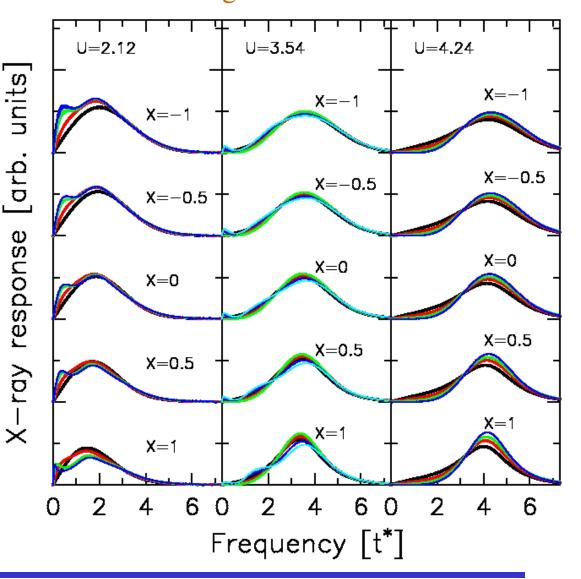
Nonresonant B_{1g} Raman scattering (n=1,U=4.2)



- Here we see the
 expected universal
 behavior for the
 insulator---the lowenergy spectral
 weight is depleted as
 T goes to zero and an
 isosbestic point
 appears.
- The temperature
 dependence here is
 over a wider range
 than for the FK model
 due to the Tdependence of the
 interacting DOS.

Inelastic X-ray scattering (B_{1g}, zone diagonal)

- Nonresonant scattering for a correlated metal, a system that undergoes a metal-insulator transition, and a correlated insulator.
- Note how the Fermi peak
 broadens and remains away
 from ω=0 as q increases.
- In the MIT case, the scattering results depend **weakly** on T.
- For the insulator, the results are quite similar, except for **some broadening**, as one moves through the Brillouin zone.



Summary Hubbard model

- The Fermi-liquid behavior introduces new features to the B_{1g} Raman response: there is a characteristic **Drude like feature** that develops at the lowest frequencies (with a width that decreases like T²).
- New behavior occurs on the metallic side of the MIT, where the **low-energy spectral weight increases** as T decreases and where additional structure is seen, as the system undergoes a temperature-driven insulator-metal transition.
- In the insulating phase we see the expected "**universal behavior**," but the temperature dependence is slower here, because the interacting DOS is also T-dependent.

Conclusions

- Showed how an exact solution for nonresonant Raman scattering can be constructed for a system that passes through a metal-insulator transition. The solutions displayed both an isosbestic point and a rapid increase in low-frequency spectral weight near the quantum-critical point, just as seen in experiment.
- Results are **model independent** or **"universal"** on the insulating side of the metal-insulator transition, explaining why so many different correlated insulators show similar behavior.
- Found the presence of **a low frequency Drude peak** in the Fermi-liquid metals.
- Showed interesting universal features are to be expected with **inelastic x-ray scattering** as well.